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LM386

Low Voltage Audio Power Amplifier

General Description

The LM386 is a power amplifier designed for use in low voltage consumer applications. The gain is internally set to 20 to keep external part count low, but the addition of an external resistor and capacitor between pins 1 and 8 will increase the gain to any value from 20 to 200.

The inputs are ground referenced while the output automatically biases to one-half the supply voltage. The quiescent power drain is only 24 milliwatts when operating from a 6 volt supply, making the LM386 ideal for battery operation.

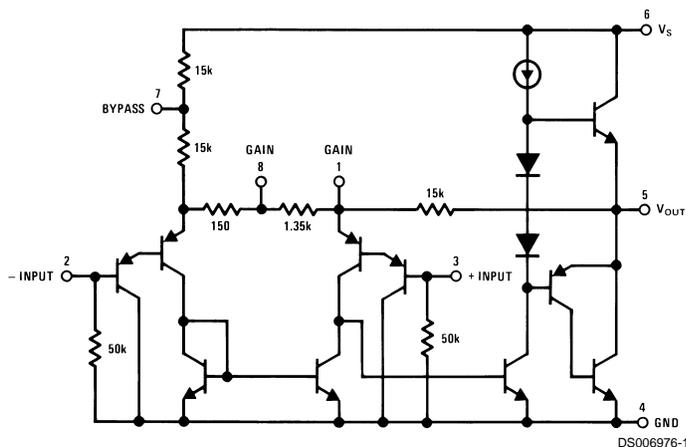
Features

- Battery operation
- Minimum external parts
- Wide supply voltage range: 4V–12V or 5V–18V
- Low quiescent current drain: 4mA
- Voltage gains from 20 to 200
- Ground referenced input
- Self-centering output quiescent voltage
- Low distortion: 0.2% ($A_V = 20$, $V_S = 6V$, $R_L = 8\Omega$, $P_O = 125mW$, $f = 1kHz$)
- Available in 8 pin MSOP package

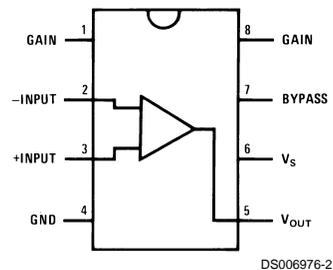
Applications

- AM-FM radio amplifiers
- Portable tape player amplifiers
- Intercoms
- TV sound systems
- Line drivers
- Ultrasonic drivers
- Small servo drivers
- Power converters

Equivalent Schematic and Connection Diagrams



Small Outline,
Molded Mini Small Outline,
and Dual-In-Line Packages



Top View

Order Number LM386M-1,
LM386MM-1, LM386N-1,
LM386N-3 or LM386N-4
See NS Package Number
M08A, MUA08A or N08E

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (LM386N-1, -3, LM386M-1)	15V
Supply Voltage (LM386N-4)	22V
Package Dissipation (Note 3) (LM386N)	1.25W
(LM386M)	0.73W
(LM386MM-1)	0.595W
Input Voltage	±0.4V
Storage Temperature	-65°C to +150°C
Operating Temperature	0°C to +70°C
Junction Temperature	+150°C
Soldering Information	

Dual-In-Line Package	
Soldering (10 sec)	+260°C
Small Outline Package (SOIC and MSOP)	
Vapor Phase (60 sec)	+215°C
Infrared (15 sec)	+220°C
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.	
Thermal Resistance	
θ_{JC} (DIP)	37°C/W
θ_{JA} (DIP)	107°C/W
θ_{JC} (SO Package)	35°C/W
θ_{JA} (SO Package)	172°C/W
θ_{JA} (MSOP)	210°C/W
θ_{JC} (MSOP)	56°C/W

Electrical Characteristics (Notes 1, 2)

$T_A = 25^\circ\text{C}$

Parameter	Conditions	Min	Typ	Max	Units
Operating Supply Voltage (V_S) LM386N-1, -3, LM386M-1, LM386MM-1 LM386N-4		4 5		12 18	V
Quiescent Current (I_Q)	$V_S = 6\text{V}, V_{IN} = 0$		4	8	mA
Output Power (P_{OUT}) LM386N-1, LM386M-1, LM386MM-1 LM386N-3 LM386N-4	$V_S = 6\text{V}, R_L = 8\Omega, \text{THD} = 10\%$ $V_S = 9\text{V}, R_L = 8\Omega, \text{THD} = 10\%$ $V_S = 16\text{V}, R_L = 32\Omega, \text{THD} = 10\%$	250 500 700	325 700 1000		mW
Voltage Gain (A_V)	$V_S = 6\text{V}, f = 1\text{ kHz}$ 10 μF from Pin 1 to 8		26 46		dB
Bandwidth (BW)	$V_S = 6\text{V}, \text{Pins 1 and 8 Open}$		300		kHz
Total Harmonic Distortion (THD)	$V_S = 6\text{V}, R_L = 8\Omega, P_{OUT} = 125\text{ mW}$ $f = 1\text{ kHz}, \text{Pins 1 and 8 Open}$		0.2		%
Power Supply Rejection Ratio (PSRR)	$V_S = 6\text{V}, f = 1\text{ kHz}, C_{BYPASS} = 10\ \mu\text{F}$ Pins 1 and 8 Open, Referred to Output		50		dB
Input Resistance (R_{IN})			50		k Ω
Input Bias Current (I_{BIAS})	$V_S = 6\text{V}, \text{Pins 2 and 3 Open}$		250		nA

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: For operation in ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and 1) a thermal resistance of 107°C/W junction to ambient for the dual-in-line package and 2) a thermal resistance of 170°C/W for the small outline package.

Application Hints

GAIN CONTROL

To make the LM386 a more versatile amplifier, two pins (1 and 8) are provided for gain control. With pins 1 and 8 open the 1.35 k Ω resistor sets the gain at 20 (26 dB). If a capacitor is put from pin 1 to 8, bypassing the 1.35 k Ω resistor, the gain will go up to 200 (46 dB). If a resistor is placed in series with the capacitor, the gain can be set to any value from 20 to 200. Gain control can also be done by capacitively coupling a resistor (or FET) from pin 1 to ground.

Additional external components can be placed in parallel with the internal feedback resistors to tailor the gain and frequency response for individual applications. For example, we can compensate poor speaker bass response by frequency shaping the feedback path. This is done with a series RC from pin 1 to 5 (paralleling the internal 15 k Ω resistor). For 6 dB effective bass boost: $R \approx 15$ k Ω , the lowest value for good stable operation is $R = 10$ k Ω if pin 8 is open. If pins 1 and 8 are bypassed then R as low as 2 k Ω can be used. This restriction is because the amplifier is only compensated for closed-loop gains greater than 9.

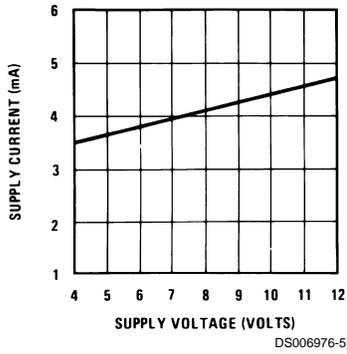
INPUT BIASING

The schematic shows that both inputs are biased to ground with a 50 k Ω resistor. The base current of the input transistors is about 250 nA, so the inputs are at about 12.5 mV when left open. If the dc source resistance driving the LM386 is higher than 250 k Ω it will contribute very little additional offset (about 2.5 mV at the input, 50 mV at the output). If the dc source resistance is less than 10 k Ω , then shorting the unused input to ground will keep the offset low (about 2.5 mV at the input, 50 mV at the output). For dc source resistances between these values we can eliminate excess offset by putting a resistor from the unused input to ground, equal in value to the dc source resistance. Of course all offset problems are eliminated if the input is capacitively coupled.

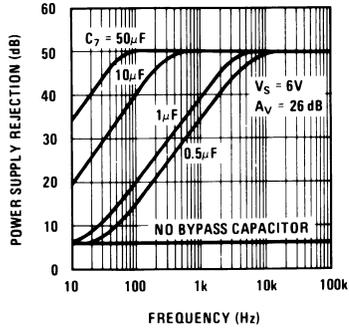
When using the LM386 with higher gains (bypassing the 1.35 k Ω resistor between pins 1 and 8) it is necessary to bypass the unused input, preventing degradation of gain and possible instabilities. This is done with a 0.1 μ F capacitor or a short to ground depending on the dc source resistance on the driven input.

Typical Performance Characteristics

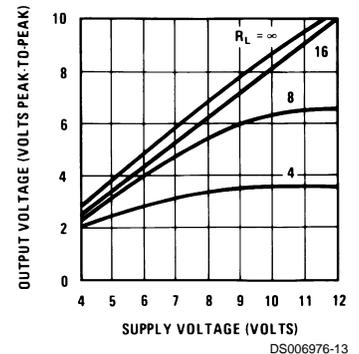
Quiescent Supply Current vs Supply Voltage



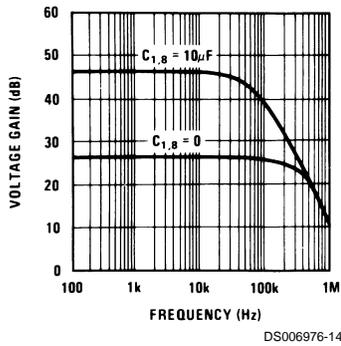
Power Supply Rejection Ratio (Referred to the Output) vs Frequency



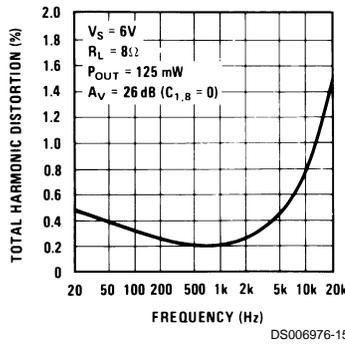
Peak-to-Peak Output Voltage Swing vs Supply Voltage



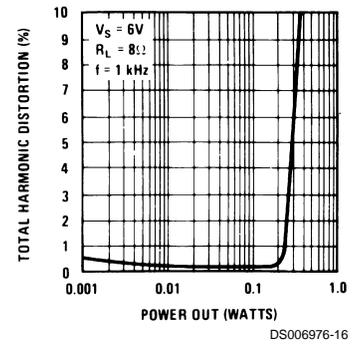
Voltage Gain vs Frequency



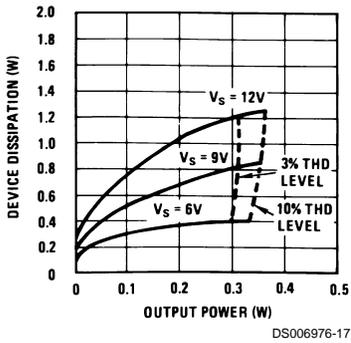
Distortion vs Frequency



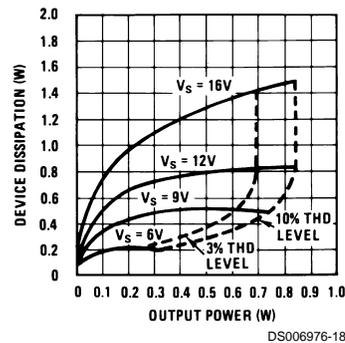
Distortion vs Output Power



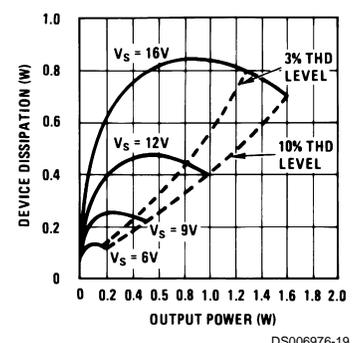
Device Dissipation vs Output Power—4Ω Load



Device Dissipation vs Output Power—8Ω Load

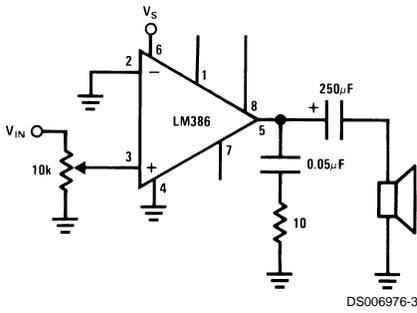


Device Dissipation vs Output Power—16Ω Load

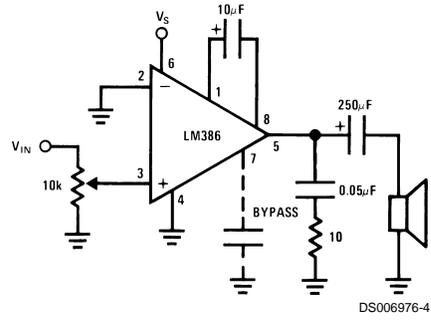


Typical Applications

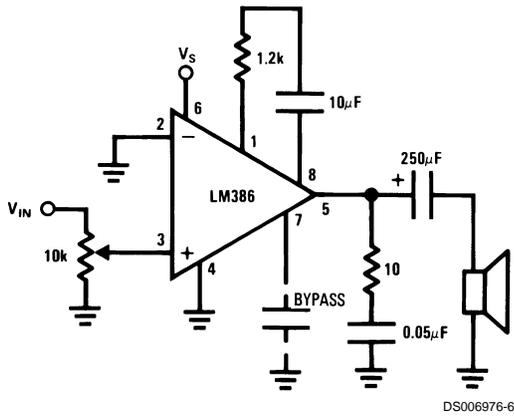
**Amplifier with Gain = 20
Minimum Parts**



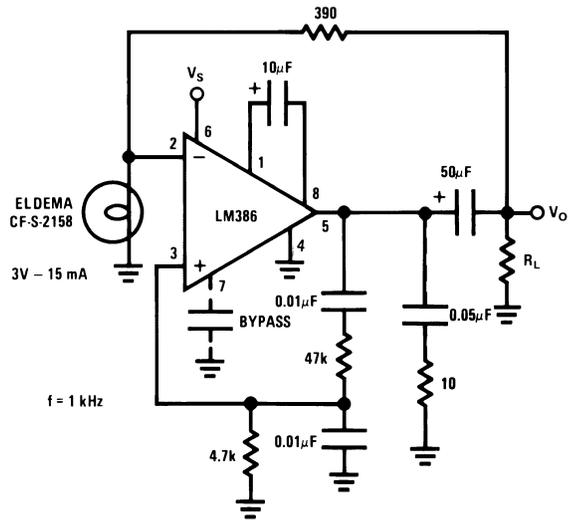
Amplifier with Gain = 200



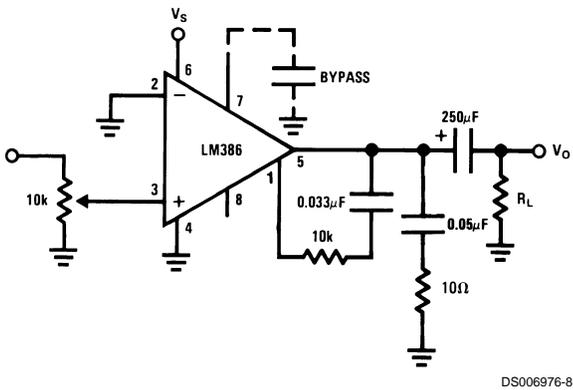
Amplifier with Gain = 50



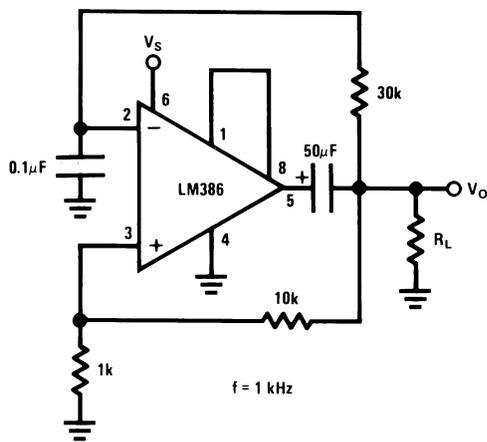
Low Distortion Power Wienbridge Oscillator



Amplifier with Bass Boost

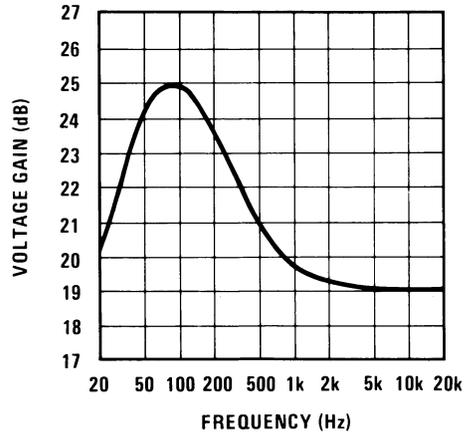


Square Wave Oscillator



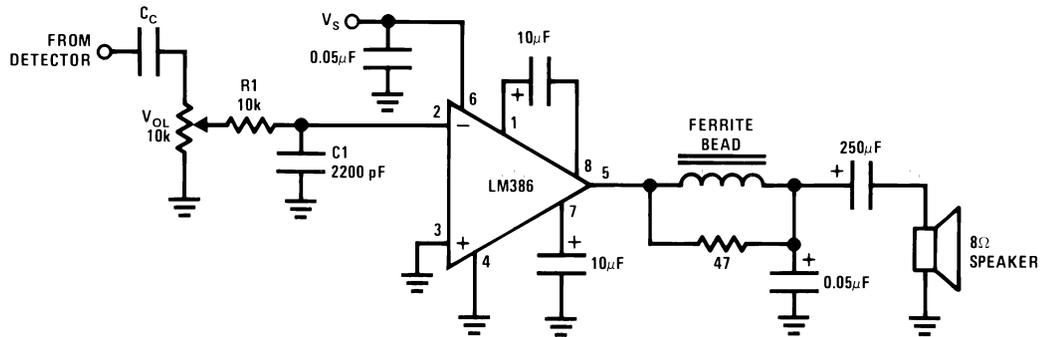
Typical Applications (Continued)

Frequency Response with Bass Boost



DS006976-10

AM Radio Power Amplifier



DS006976-11

Note 4: Twist Supply lead and supply ground very tightly.

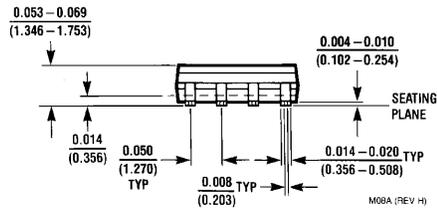
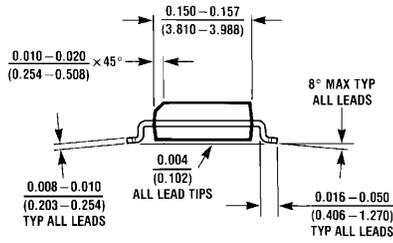
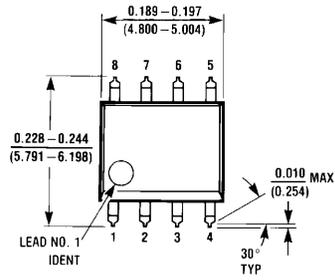
Note 5: Twist speaker lead and ground very tightly.

Note 6: Ferrite bead in Ferroxcube K5-001-001/3B with 3 turns of wire.

Note 7: R1C1 band limits input signals.

Note 8: All components must be spaced very closely to IC.

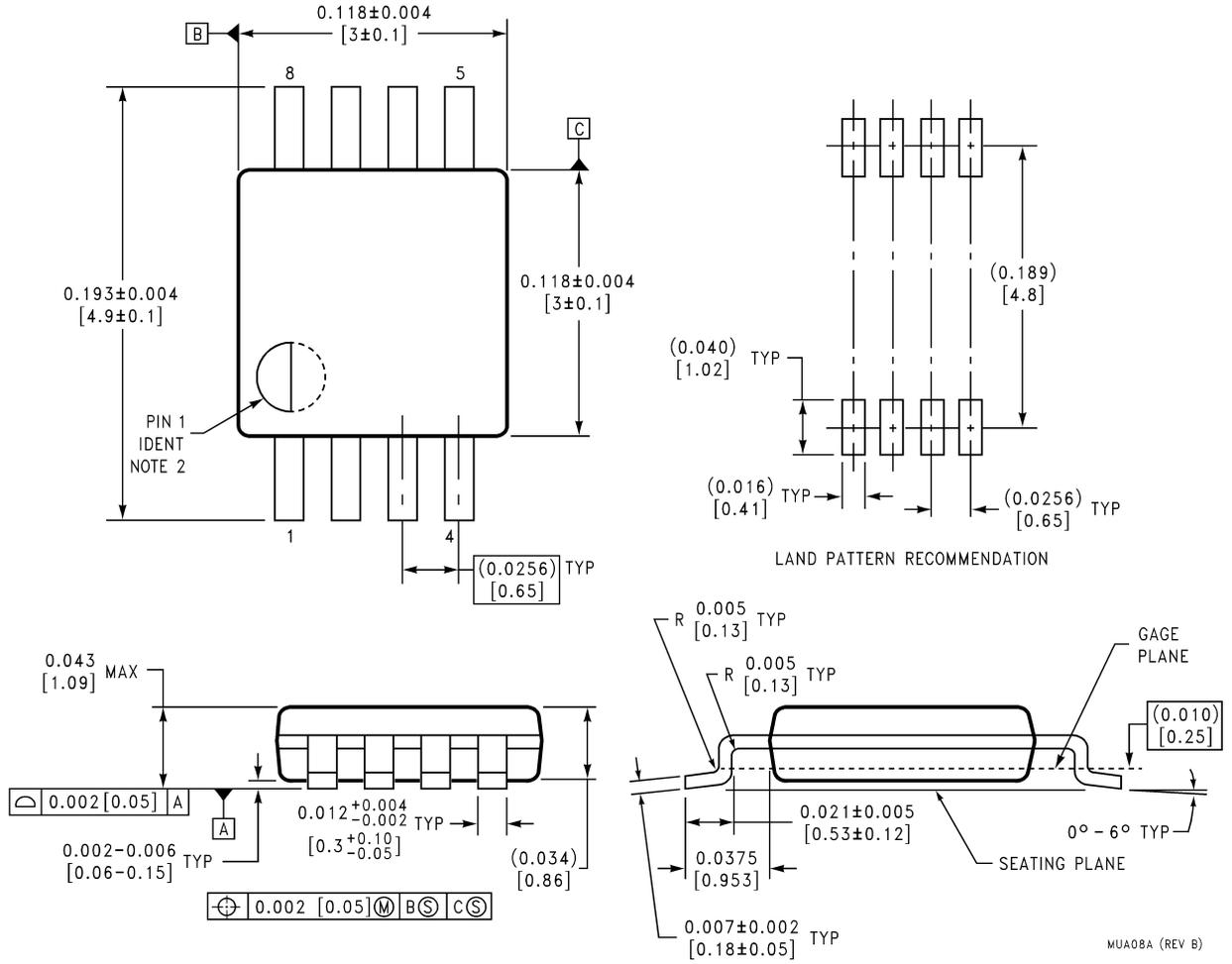
Physical Dimensions inches (millimeters) unless otherwise noted



SO Package (M)
Order Number LM386M-1
NS Package Number M08A

M08A (REV H)

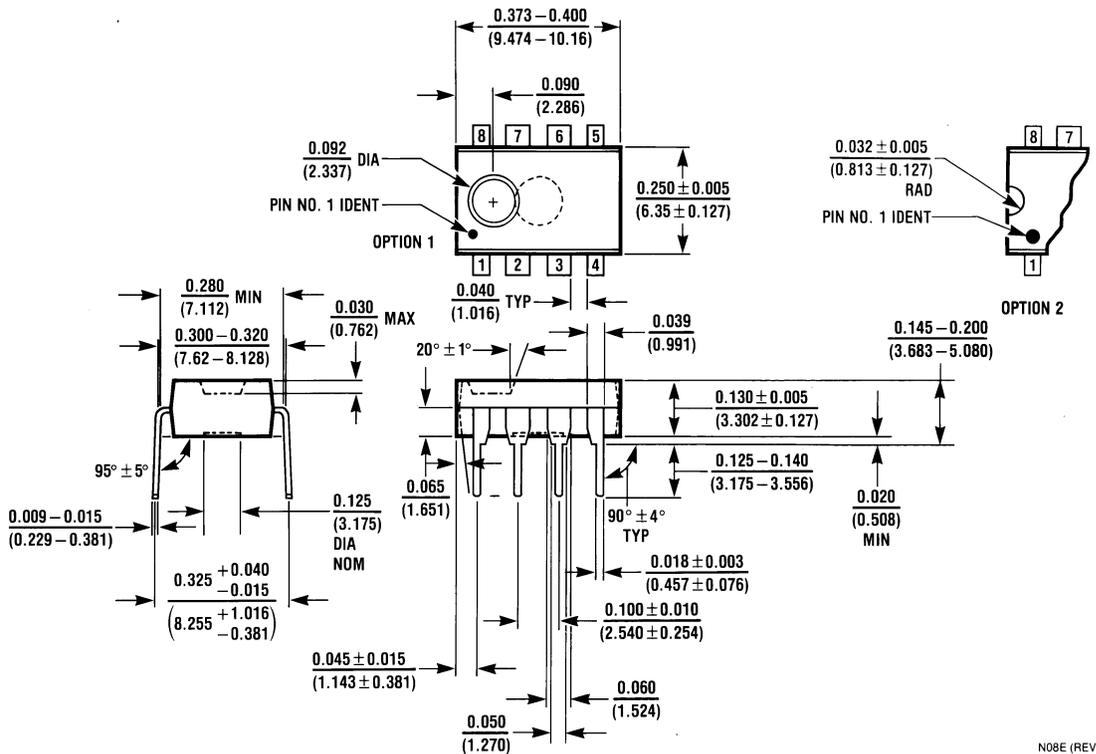
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



8-Lead (0.118" Wide) Molded Mini Small Outline Package
Order Number LM386MM-1
NS Package Number MUA08A

MUA08A (REV B)

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



N08E (REV F)

Dual-In-Line Package (N)
Order Number LM386N-1, LM386N-3 or LM386N-4
NS Package Number N08E

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Low Voltage Audio Power Amplifier

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[Features](#)

[Datasheet](#)

[Package & Models](#)

[Samples & Pricing](#)

[Application Notes](#)

Parametric Table

Number of Channels	1
User Supply Voltage	12 V
Power Supply Range	+4 - +18 V
Power at 4 Ohms, THD < /= 1% (Watt)	.25
Power at 8 Ohms, THD < /= 1% (Watt)	.25

Parametric Table

Power at 4 Ohms, THD < /= 10% (Watt)	.32
Power at 8 Ohms, THD < /= 10% (Watt)	.3250
PSRR (dB)	-
Typical THD Rating (%)	.25
THD Measurement Conditions	Po=0.125W @ Vs=6V

Datasheet

Title	Size in Kbytes	Date	View Online	Download	Receive via Email
LM386 Low Voltage Audio Power Amplifier	264 Kbytes	10-Aug-00	View Online	Download	Receive via Email
LM386 Low Voltage Audio Power Amplifier (JAPANESE)	252 Kbytes		View Online	Download	Receive via

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Package Availability, Models, Samples & Pricing

Part Number	Package			Status	Models		Samples & Electronic Orders	Budgetary Pricing		Std Pack Size	Package Marking
	Type	Pins	MSL		SPICE	IBIS		Qty	\$US each		
LM386M-1	SOIC NARROW	8	MSL	Full production	N/A	N/A	24 Hour Buy Now	1K+	\$0.1500	reel of 95	[logo]c2cT LM386 M-1
LM386MX-1	SOIC NARROW	8	MSL	Full production	N/A	N/A	Buy Now	1K+	\$0.1500	reel of 2500	[logo]c2cT LM386 M-1

LM386MM-1	MINI SOIC	8	MSL	Full production	N/A	N/A	Samples Buy Now	1K+	\$0.2000	reel of 1000	cZc1cT Z86
LM386MMX-1	MINI SOIC	8	MSL	Full production	N/A	N/A		1K+	\$0.2000	reel of 3500	cZc1cT Z86
LM386N-1	MDIP	8	MSL	Full production	N/A	N/A	24 Hour Buy Now	1K+	\$0.1550	rail of 40	[logo]cUcZc2cT LM 386N-1
LM386N-3	MDIP	8	MSL	Full production	N/A	N/A	24 Hour Buy Now	1K+	\$0.2500	rail of 40	[logo]cUcZc2cT LM 386N-3
LM386N-4	MDIP	8	MSL	Full production	N/A	N/A	24 Hour Buy Now	1K+	\$0.3000	rail of 40	[logo]cUcZc2cT LM 386N-4
LM386-1 MDA	Die			Full production	N/A	N/A	Samples			tray of N/A	-
LM386-3 MDA	Die			Full production	N/A	N/A	Samples			tray of N/A	-
LM386-4 MDA	Die			Full production	N/A	N/A	Samples			tray of N/A	-
LM386-1 MWA	Wafer			Full production	N/A	N/A				wafer jar of N/A	-
LM386-3 MWA	Wafer			Full production	N/A	N/A				wafer jar of N/A	-
LM386-4 MWA	Wafer			Full production	N/A	N/A				wafer jar of N/A	-

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- Small servo drivers
- Power converters

Application Notes

Title	Size in Kbytes	Date	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
			View Online	Download	Receive via Email
AN-263: Sine Wave Generation Techniques	223 Kbytes	4-Nov-95	View Online	Download	Receive via Email
AN-147: Low Cost IC Stereo Receiver	140 Kbytes	4-Nov-95	View Online	Download	Receive via Email
AN-512: DS8911 AM/FM/TV Sound Up-Conversion Frequency Synthesizer	232 Kbytes	4-Nov-95	View Online	Download	Receive via Email

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